

L Number	Hits	Search Text	DB	Time stamp
1	709009	non-volatile memory cell	USPAT	2003/02/10 15:24
2	3298	plurality same (threshold adj voltage)	USPAT	2003/02/10 15:25
3	2311	(non-volatile memory cell) and (plurality same (threshold adj voltage))	USPAT	2003/02/10 15:25
4	1098	((non-volatile memory cell) and (plurality same (threshold adj voltage))) and program\$4	USPAT	2003/02/10 15:26
5	523	((non-volatile memory cell) and (plurality same (threshold adj voltage))) and program\$4) and (inhibit\$3 or verify\$3)	USPAT	2003/02/10 15:27
6	399	((non-volatile memory cell) and (plurality same (threshold adj voltage))) and program\$4) and (inhibit\$3 or verify\$3)) and (reach\$2 or exceed\$2)	USPAT	2003/02/10 15:29
7	330	((non-volatile memory cell) and (plurality same (threshold adj voltage))) and program\$4) and (inhibit\$3 or verify\$3)) and (reach\$2 or exceed\$2)) and charge	USPAT	2003/02/10 15:30
8	11	((non-volatile memory cell) and (plurality same (threshold adj voltage))) and program\$4) and (inhibit\$3 or verify\$3)) and (reach\$2 or exceed\$2)) and charge) and (first adj set) and (second adj set)	USPAT	2003/02/10 15:31

L Number	Hits	Search Text	DB	Time stamp
1	513	(second adj set) same (memory adj cell)	USPAT	2003/02/24 10:31
2	251	((second adj set) same (memory adj cell)) and charge	USPAT	2003/02/24 10:31
3	121	((second adj set) same (memory adj cell)) and charge) and predetermine\$1	USPAT	2003/02/24 10:32
4	84	((second adj set) same (memory adj cell)) and charge) and predetermine\$1) and program\$4	USPAT	2003/02/24 10:32
5	8	((second adj set) same (memory adj cell)) and charge) and predetermine\$1) and program\$4) and inhibit\$3	USPAT	2003/02/24 10:33